

Fast Recovery Epitaxial Diode (FRED)

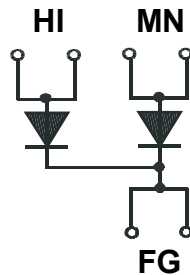
PSEK 60

$$I_{FAVM} = 2 \times 34 \text{ A}$$

$$V_{RRM} = 200 \text{ V}$$

$$t_{rr} = 35 \text{ ns}$$

Preliminary Data Sheet



V_{RSM} (V)	V_{RRM} (V)	Type
200	200	PSEK 60/02

Symbol	Test Conditions	Maximum Ratings	
I_{FRMS}	$T_{VJ} = T_{VJM}$	50	A
I_{FAVM}^*	$T_C = 115^\circ\text{C}$, rectangular, $d=0.5$	34	A
I_{FRM}	$t_p < 10\mu\text{s}$; rep. rating, pulse width limited by T_{VJM}	375	A
I_{FSM}	$T_{VJ} = 45^\circ\text{C}$ $t = 10 \text{ ms}$ (50 Hz), sine	325	A
	$V_R = 0$ $t = 8.3 \text{ ms}$ (60 Hz), sine	350	A
	$T_{VJ} = 125^\circ\text{C}$ $t = 10 \text{ ms}$ (50 Hz), sine	290	A
	$V_R = 0$ $t = 8.3 \text{ ms}$ (60 Hz), sine	310	A
$\int i^2 dt$	$T_{VJ} = 45^\circ\text{C}$ $t = 10 \text{ ms}$ (50 Hz), sine	530	A ² s
	$V_R = 0$ $t = 8.3 \text{ ms}$ (60 Hz), sine	510	A ² s
	$T_{VJ} = 125^\circ\text{C}$ $t = 10 \text{ ms}$ (50 Hz), sine	420	A ² s
	$V_R = 0$ $t = 8.3 \text{ ms}$ (60 Hz), sine	400	A ² s
T_{VJ}		-40... + 150	°C
T_{VJM}		150	°C
T_{stg}		-40... + 150	°C
V_{ISOL}	50/60 Hz, RMS $t = 1 \text{ min}$	2500	V~
	$I_{ISOL} \leq 1 \text{ mA}$ $t = 1 \text{ s}$	3000	V~
M_d	Mounting torque (M4)	1.5 - 1.8	Nm
		14 - 16	lb.in.
Weight	typ.	16	g

Symbol	Test Conditions	Characteristic Value	
I_R	$T_{VJ} = 25^\circ\text{C}$, $V_R = V_{RRM}$	max.	200 μA
	$T_{VJ} = 25^\circ\text{C}$, $V_R = 0.8 \cdot V_{RRM}$	max.	50 μA
	$T_{VJ} = 125^\circ\text{C}$, $V_R = 0.8 \cdot V_{RRM}$	max.	5 mA
V_F	$I_F = 30 \text{ A}$, $T_{VJ} = 25^\circ\text{C}$	max.	1.10 V
V_{TO}	For power-loss calculations only		0.72 V
r_T			4.2 $\text{m}\Omega$
R_{thJC}	per diode; max.		1.25 K/W
R_{thCH}	per diode; typ.		0.05 K/W
I_{RM}	$I_F = 30 \text{ A}$; $-di_F/dt = 100 \text{ A}/\mu\text{s}$; $V_R = 100 \text{ V}$ $L \leq 0.05 \text{ mH}$; $T_{VJ} = 100^\circ\text{C}$	typ.	4 A
t_{rr}	$I_F = 1 \text{ A}$; $-di_F/dt = 100 \text{ A}/\mu\text{s}$; $V_R = 30 \text{ V}$; $T_{VJ} = 25^\circ\text{C}$	typ.	35 ns
d_s	Creeping distance on surface	11.2	mm
d_A	Creeping distance in air	12.8	mm
a	Max. allowable acceleration	50	m/s^2

Features

- Isolation voltage 3000 V~
- Planar glass passivated chips
- Low forward voltage drop
- Leads suitable for PC board soldering
- Very short recovery time
- Extremely low switching losses
- UL registered, E 148688

Applications

- Antiparallel diode for high frequency switching devices
- Anti saturation diode
- Snubber diode
- Free wheeling diode in converters and motor control circuits
- Rectifiers in switch mode power supplies (SMPS)
- Inductive heating and melting
- Uninterruptible power supplies (UPS)
- Ultrasonic cleaners and welders

Advantages

- Easy to mount with two screws
- Space and weight savings
- Improved temperature and power cycling capability
- Low noise switching
- Small and light weight

Data according to IEC 60747 refer to a single diode unless otherwise stated

* I_{FAVM} rating includes blocking losses at T_{VJM} ;
 $V_R = 0.8 V_{RRM}$; duty cycle $d = 0.5$

Package style and outline

Dimensions in mm (1mm = 0.0394")

